

June 2014

FDMA910PZ

Single P-Channel PowerTrench® MOSFET -20 V, -9.4 A, 20 m Ω

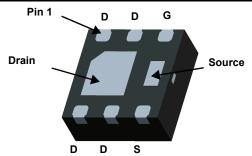
Features

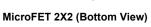
- Max $r_{DS(on)}$ = 20 m Ω at V_{GS} = -4.5 V, I_D = -9.4 A
- Max $r_{DS(on)}$ = 24 m Ω at V_{GS} = -2.5 V, I_D = -8.6 A
- Max $r_{DS(on)}$ = 34 m Ω at V_{GS} = -1.8 V, I_D = -7.2 A
- Low Profile 0.8 mm maximum in the new package MicroFET 2x2 mm
- HBM ESD protection level > 2.8k V typical (Note 3)
- Free from halogenated compounds and antimony oxides
- RoHS Compliant

General Description

This device is designed specifically for battery charge or load switching in cellular handset and other ultraportable applications. It features a MOSFET with low on-state resistance and zener diode protection against ESD. The MicroFET 2X2 package offers exceptional thermal performance for its physical size and is well suited to linear mode applications.







D 1 6 D D 2 5 D G 3 4 S

MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Param	eter		Ratings	Units
V_{DS}	Drain to Source Voltage			-20	V
V_{GS}	Gate to Source Voltage			±8	V
	-Continuous	T _A = 25°C	(Note 1a)	-9.4	^
'D	-Pulsed			-45	Α
D	Power Dissipation	T _A = 25°C	(Note 1a)	2.4	10/
P_{D}	Power Dissipation	T _A = 25°C	(Note 1b)	0.9	W
T _J , T _{STG}	Operating and Storage Junction Tempera	ature Range		-55 to +150	°C

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	52	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	145	C/VV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
910	FDMA910PZ	MicroFET 2X2	7"	8 mm	3000 units

Electrical Characteristics $T_J = 25$ °C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	acteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	$I_D = -250 \mu A, V_{GS} = 0 V$	-20			V
$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	I_D = -250 μA, referenced to 25 °C		-12		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = -16 V, V _{GS} = 0 V			-1	μА
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 8 \text{ V}, V_{DS} = 0 \text{ V}$			±1	μΑ

On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = -250 \mu A$	-0.4	-0.5	-1.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I_D = -250 μ A, referenced to 25 °C		3		mV/°C
	$V_{GS} = -4.5 \text{ V}, I_D = -9.4 \text{ A}$		16	20		
		$V_{GS} = -2.5 \text{ V}, I_D = -8.6 \text{ A}$		19	24	
r _{DS(on)}	r _{DS(on)} Static Drain to Source On Resistance	$V_{GS} = -1.8 \text{ V}, I_D = -7.2 \text{ A}$		24	34	mΩ
	$V_{GS} = -4.5 \text{ V}, I_D = -9.4 \text{ A},$ $T_J = 125 ^{\circ}\text{C}$		20	25		
9 _{FS}	Forward Transconductance	$V_{DD} = -5 \text{ V}, I_{D} = -9.4 \text{ A}$		52		S

Dynamic Characteristics

C _{iss}	Input Capacitance	V - 40 V V - 0 V	2110	2805	pF
C _{oss}	Output Capacitance	V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz	414	620	pF
C _{rss}	Reverse Transfer Capacitance	1 - 1 1011 12	388	580	pF

Switching Characteristics

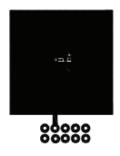
t _{d(on)}	Turn-On Delay Time			9.4	19	ns
t _r	Rise Time	V _{DD} = -10 V, I _D = -9.4 A,	V_{DD} = -10 V, I_{D} = -9.4 A, V_{GS} = -4.5 V, R_{GEN} = 6 Ω		34	ns
t _{d(off)}	Turn-Off Delay Time	V _{GS} = -4.5 V, R _{GEN} = 612			216	ns
t _f	Fall Time			103	165	ns
Q_g	Total Gate Charge	V _{GS} = -4.5 V, V _{DD} = -10 V,		21	29	nC
Q_{gs}	Gate to Source Charge	I _D = -9.4 A		2.5		nC
Q _{gd}	Gate to Drain "Miller" Charge			6		nC

Drain-Source Diode Characteristics

Tyon 15001ce to Drain Diode Forward Voltage	Source to Drain Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_S = -2 \text{ A}$ (Note 2)		-0.6	-1.2	V
	$V_{GS} = 0 \text{ V}, I_{S} = -9.4 \text{ A}$ (Note 2)		-0.8	-1.2	٧	
t _{rr}	Reverse Recovery Time	-I _F = -9.4 A, di/dt = 100 A/μs		23	37	ns
Q _{rr}	Reverse Recovery Charge			6.3	13	nC

NOTES

^{1.} R_{0,JA} is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{0,JC} is guaranteed by design while R_{0,JA} is determined by the user's board design.



a. 52 °C/W when mounted on a 1 in² pad of 2 oz copper.



b. 145 °C/W when mounted on a minimum pad of 2 oz copper.

- 2. Pulse Test: Pulse Width < 300 μs , Duty cycle < 2.0%.
- 3. The diode connected between the gate and source serves only as protection against ESD. No gate overvoltage rating is implied.

Typical Characteristics T_J = 25 °C unless otherwise noted

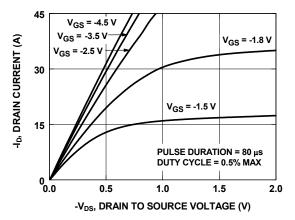


Figure 1. On-Region Characteristics

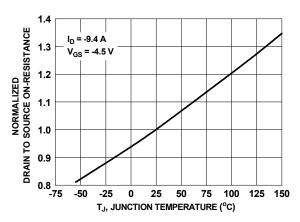


Figure 3. Normalized On-Resistance vs Junction Temperature

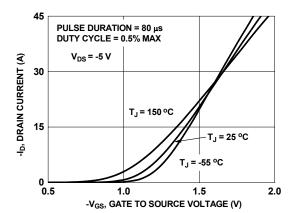


Figure 5. Transfer Characteristics

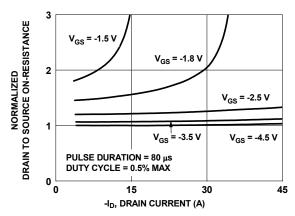


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

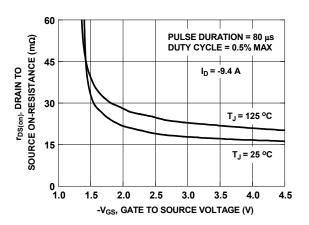


Figure 4. On-Resistance vs Gate to Source Voltage

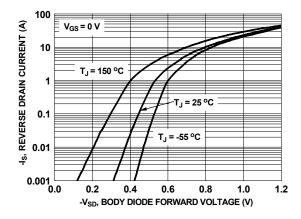


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

Typical Characteristics $T_J = 25$ °C unless otherwise noted

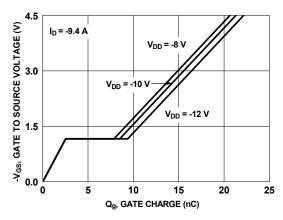


Figure 7. Gate Charge Characteristics

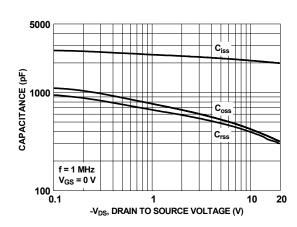


Figure 8. Capacitance vs Drain to Source Voltage

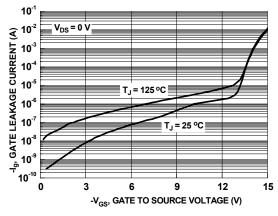


Figure 9. Gate Leakage Current vs Gate to Source Voltage

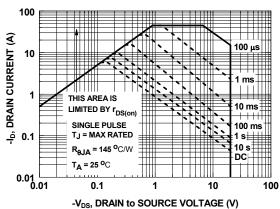


Figure 10. Forward Bias Safe
Operating Area

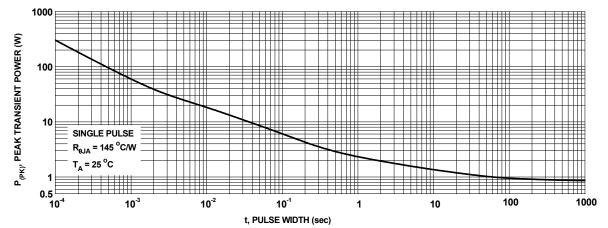


Figure 11. Single Pulse Maximum Power Dissipation

Typical Characteristics T_J = 25 °C unless otherwise noted

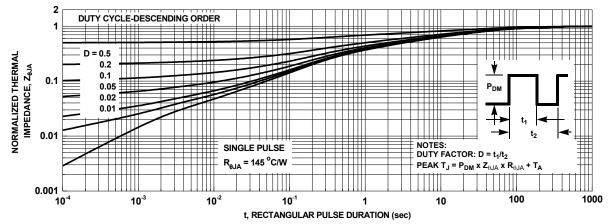
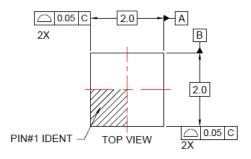
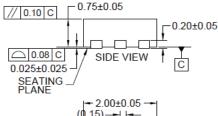
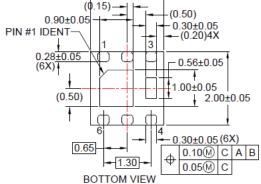


Figure 12. Junction-to-Ambient Transient Thermal Response Curve

Dimensional Outline and Pad Layout

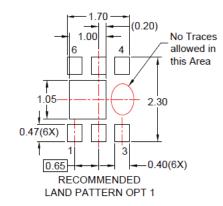


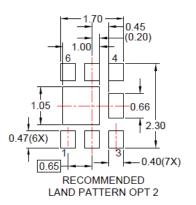




NOTES:

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401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd Minhang District, Shanghai , China

> Sales:

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

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Customer Service :

Email service@ameya360.com

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Tel +86 (21) 64016692-8333

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